

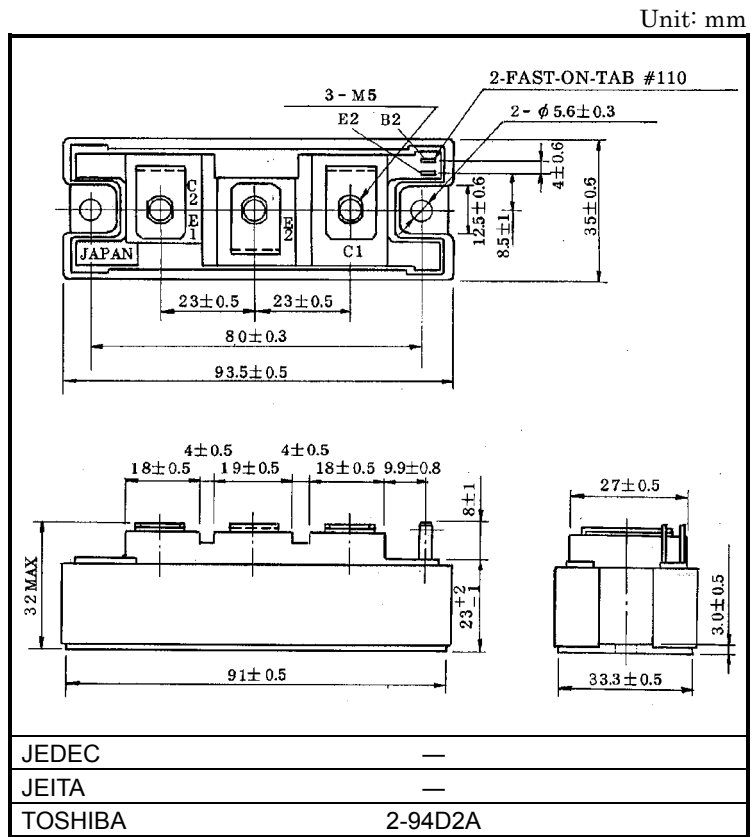
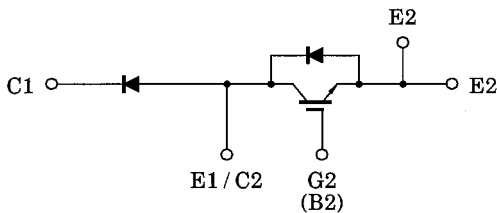
TOSHIBA GTR Module Silicon N Channel IGBT

MG100J1ZS40

High Power Switching Applications
Motor Control Applications

- High input impedance
- High speed : $t_f = 0.35\mu s$ (max)
 $t_{rr} = 0.15\mu s$ (max)
- Low saturation voltage : $V_{CE(sat)} = 3.5V$ (max)
- Enhancement-mode
- The electrodes are isolated from case.

Equivalent Circuit



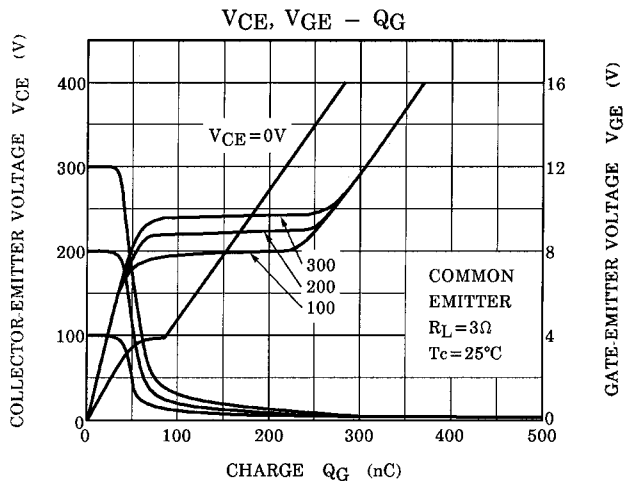
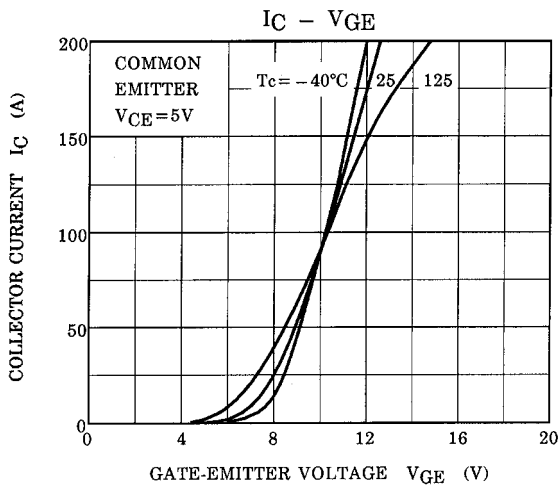
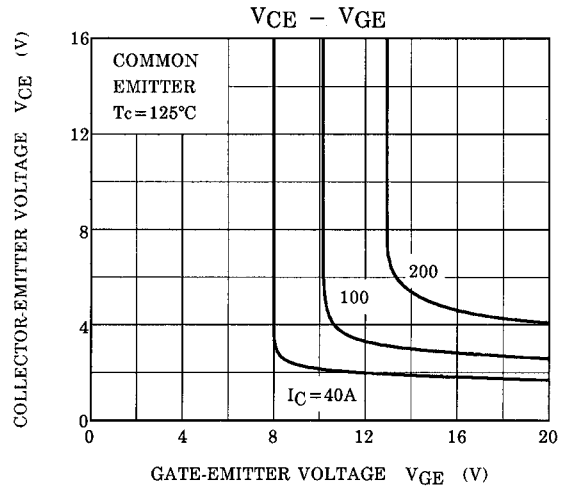
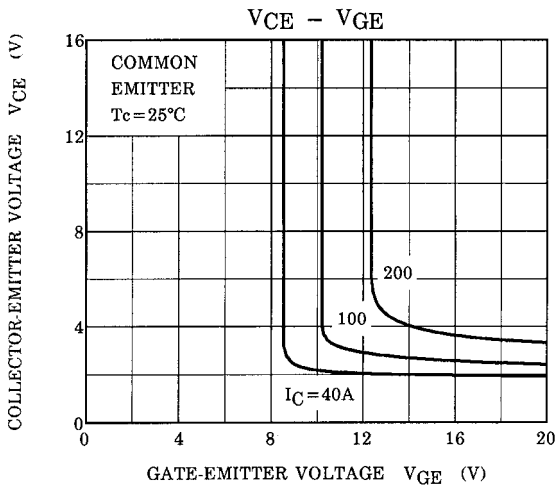
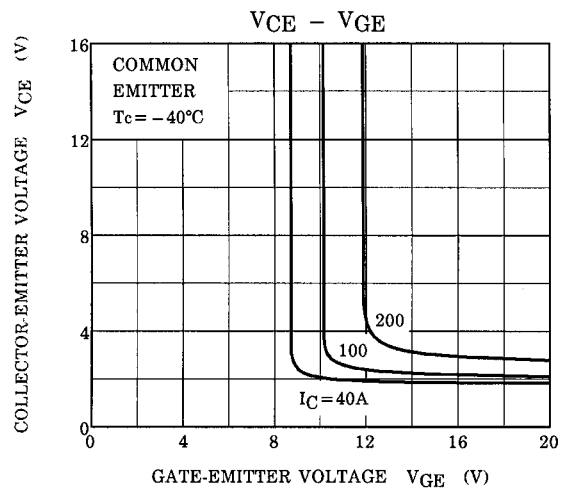
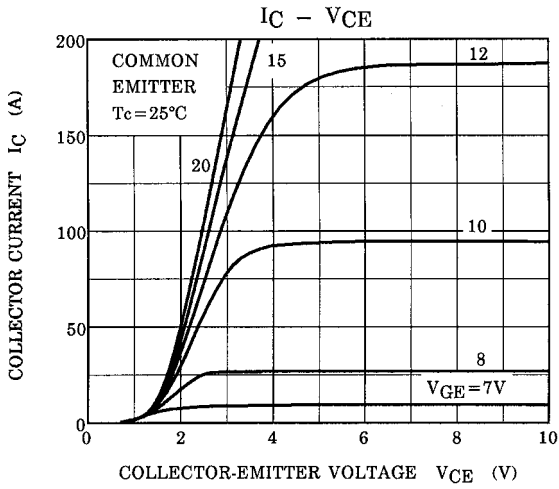
Weight: 202g

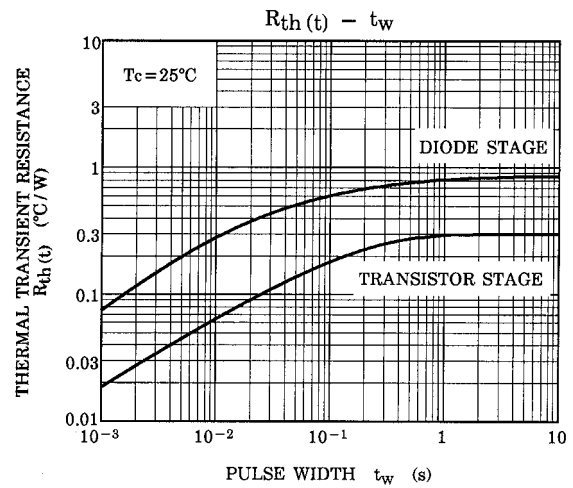
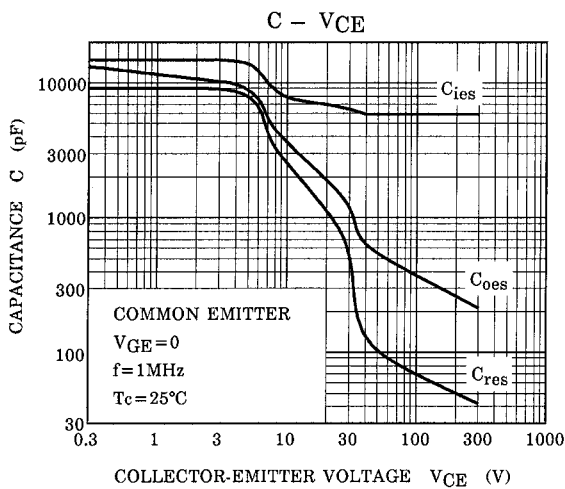
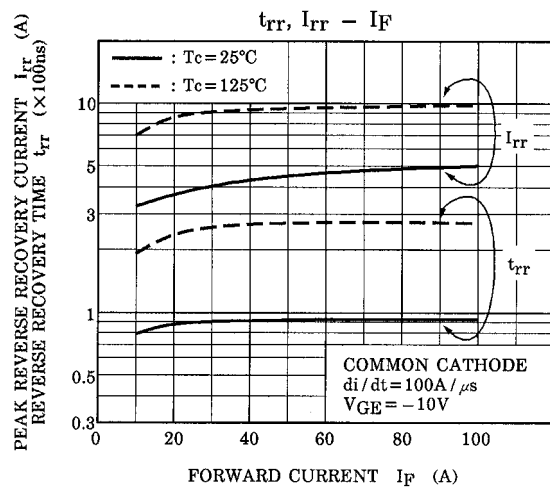
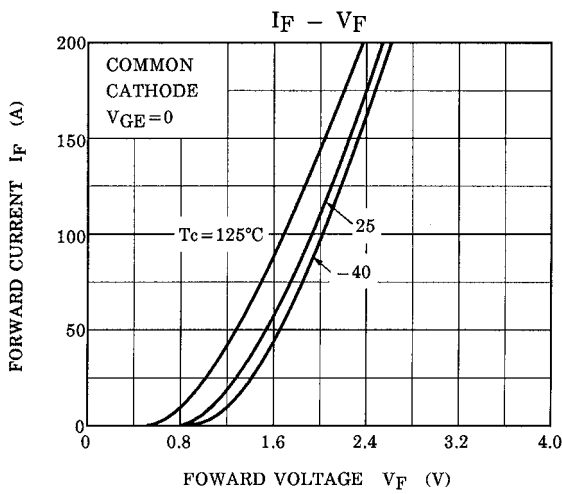
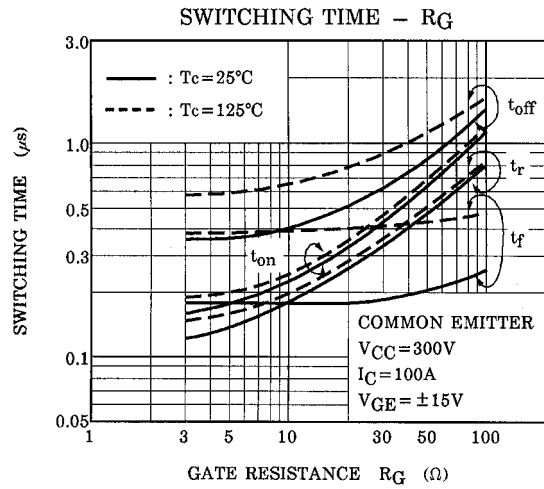
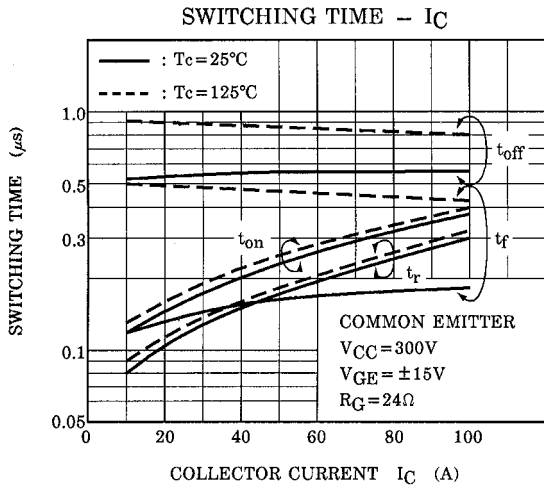
Maximum Ratings (Ta = 25°C)

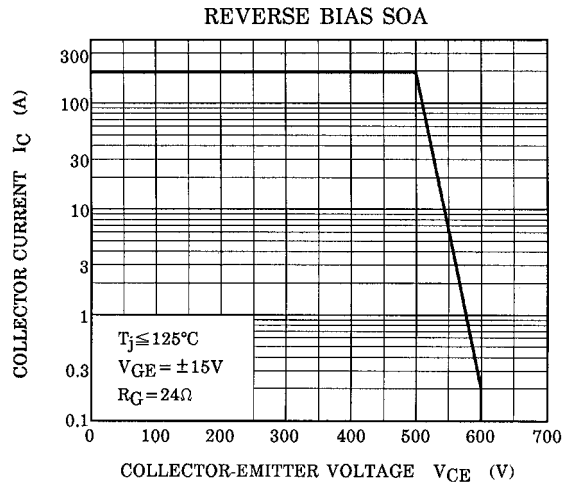
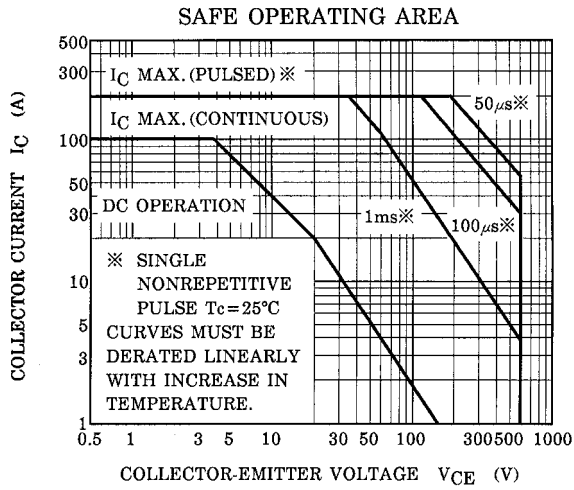
Characteristics	Symbol	Rating	Unit
Collector-emitter voltage	V_{CES}	600	V
Gate-emitter voltage	V_{GES}	±20	V
Reverse voltage	V_R	600	V
Collector current	DC	I_C	100
	1ms	I_{CP}	200
Forward current	DC	I_F	100
	1ms	I_{FM}	200
Collector power dissipation (Tc = 25°C)	P_C	400	W
Junction temperature	T_j	150	°C
Storage temperature range	T_{stg}	-40 ~ 125	°C
Isolation voltage	V_{Isol}	2500 (AC 1 min.)	V
Screw torque (Terminal / mounting)	—	3 / 3	N·m

Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current		I_{GES}	$V_{GE} = \pm 20V, V_{CE} = 0$	—	—	± 500	nA
Collector cut-off current		I_{CES}	$V_{CE} = 600V, V_{GE} = 0$	—	—	1.0	mA
Collector-emitter breakdown voltage		$V_{(BR) CES}$	$I_C = 10mA, V_{GE} = 0$	600	—	—	V
Gate-emitter cut-off voltage		$V_{GE (off)}$	$I_C = 100mA, V_{CE} = 5A$	3.0	—	6.0	V
Collector-emitter saturation voltage		$V_{CE (sat)}$	$I_C = 100A, V_{GE} = 15V$	—	2.7	3.5	V
Input capacitance		C_{ies}	$V_{CE} = 10V, V_{GE} = 0, f = 1MHz$	—	8100	—	pF
Switching time	Rise time	t_r		—	0.30	0.60	μs
	Turn-on time	t_{on}		—	0.40	0.80	
	Fall time	t_f		—	0.18	0.35	
	Turn-off time	t_{off}		—	0.60	1.00	
Reverse current		I_R	$V_R = 600V$	—	—	1.0	mA
Forward voltage		V_F	$I_F = 100A, V_{GE} = 0$	—	2.0	2.70	V
Reverse recovery time		t_{rr}	$I_F = 100A, V_{GE} = -10V, di/dt = 100A/\mu s$	—	0.08	0.15	μs
Thermal resistance		$R_{th (j-c)}$	Transistor	—	—	0.31	°C / W
			Diode	—	—	0.83	







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